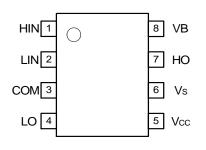


#### **Pin Diagrams**

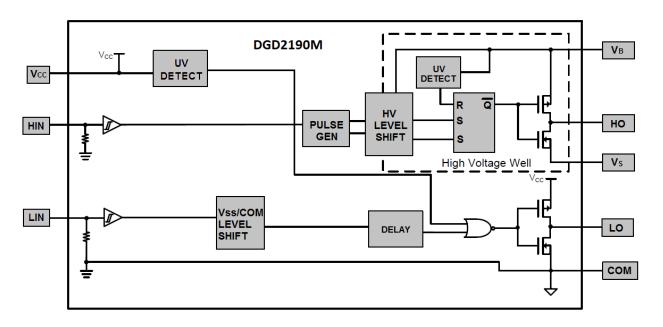


Top View: SO-8

# Pin Descriptions

| Pin Number | Pin Name        | Function   |  |
|------------|-----------------|--|--|
| 1          | HIN             | Logic Input for High-side Gate Driver Output, in Phase with HO |  |
| 2          | LIN             | Logic Input for Low-side Gate Driver Output, in Phase with LO  |  |
| 3          | COM             | Low-Side and Logic Return                                      |  |
| 4          | LO              | Low-Side Gate Drive Output                                     |  |
| 5          | V <sub>CC</sub> | Low-Side and Logic Fixed Supply                                |  |
| 6          | Vs              | High-Side Floating Supply Return                               |  |
| 7          | HO              | High-Side Gate Drive Output                                    |  |
| 8          | VB              | High-Side Floating Supply                                      |  |

# **Functional Block Diagram**





#### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                           | Symbol               | Value                                      | Unit |  |
|--|----------------------|--|------|--|
| High-Side Floating Supply Voltage        | VB                   | -0.3 to +624                               | V    |  |
| High-Side Floating Supply Offset Voltage | Vs                   | V <sub>B</sub> -24 to V <sub>B</sub> +0.3  | V    |  |
| High-Side Floating Output Voltage        | V <sub>HO</sub>      | V <sub>S</sub> -0.3 to V <sub>B</sub> +0.3 | V    |  |
| Offset Supply Voltage Transient          | dV <sub>S</sub> / dt | 50   | V/ns |  |
| Low-Side and Logic Fixed Supply Voltage  | V <sub>CC</sub>      | -0.3 to +24                                | V    |  |
| Low-Side Output Voltage                  | V <sub>LO</sub>      | -0.3 to V <sub>CC</sub> +0.3               | V    |  |
| Logic Input Voltage (HIN and LIN)        | V <sub>IN</sub>      | -0.3 to V <sub>CC</sub> +0.3               | V    |  |

#### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                                    | Symbol           | Value       | Unit |
|---|------------------|-------------|------|
| Power Dissipation Linear Derating Factor (Note 5) | PD               | 0.625       | W    |
| Thermal Resistance, Junction to Ambient (Note 5)  | R <sub>0JA</sub> | 200         | °C/W |
| Thermal Resistance, Junction to Case (Note 5)     | R <sub>θJC</sub> | 45          | °C/W |
| Operating Temperature                             | TJ               | +150        | ŝ    |
| Storage Temperature Range                         | T <sub>STG</sub> | -55 to +150 | 0    |

# **Recommended Operating Conditions**

| Parameter                                  | Symbol          | Min                | Max                | Unit |
|--|-----------------|--------------------|--------------------|------|
| High-Side Floating Supply Absolute Voltage | VB              | V <sub>S</sub> +10 | V <sub>S</sub> +20 | V    |
| High-Side Floating Supply Offset Voltage   | Vs              | (Note 6)           | 600                | V    |
| High-Side Floating Output Voltage          | V <sub>HO</sub> | Vs                 | VB                 | V    |
| Low-Side Fixed Supply Voltage              | Vcc             | 10                 | 20                 | V    |
| Low-Side Output Voltage                    | VLO             | 0                  | Vcc                | V    |
| Logic Input Voltage (HIN and LIN)          | V <sub>IN</sub> | 0                  | 5                  | V    |
| Ambient Temperature                        | T <sub>A</sub>  | -40                | +125               | °C   |

Notes: 5. When mounted on a standard JEDEC 2-layer FR-4 board. 6. Logic operation for Vs of -5V to +600V.

DGD2190M Document Number DS39672 Rev. 4 - 2 Downloaded from Arrow.com.



# **DC Electrical Characteristics** ( $V_{BIAS}$ ( $V_{CC}$ , $V_{BS}$ ) = 15V, @T<sub>A</sub> = +25°C, unless otherwise specified.) (Note 7)

| Parameter   | Symbol             | Min | Тур | Max   | Unit | Condition                    |
|---|--------------------|-----|-----|-------|------|------------------------------|
| Logic "1" Input Voltage (Note 8)                              | VIH                | 2.5 | —   | _     | V    | $V_{CC} = 10V$ to 20V        |
| Logic "0" Input Voltage (Note 8)                              | V <sub>IL</sub>    | —   | _   | 0.8   | V    | $V_{CC} = 10V$ to 20V        |
| High Level Output Voltage, V <sub>BIAS</sub> - V <sub>O</sub> | V <sub>OH</sub>    | _   | _   | 0.1   | V    | $I_O = 0 m A$                |
| Low Level Output Voltage, V <sub>O</sub>                      | V <sub>OL</sub>    | _   | -   | 0.035 | V    | $I_O = 0 m A$                |
| Offset Supply Leakage Current                                 | I <sub>LK</sub>    | _   | _   | 50    | μA   | $V_{B} = V_{S} = 600V$       |
| Quiescent V <sub>BS</sub> Supply Current                      | I <sub>BSQ</sub>   | _   | 45  | 80    | μA   | $V_{IN} = 0V \text{ or } 5V$ |
| Quiescent V <sub>CC</sub> Supply Current                      | ICCQ               | _   | 75  | 200   | μA   | $V_{IN} = 0V \text{ or } 5V$ |
| Logic "1" Input Bias Current                                  | I <sub>IN+</sub>   | _   | 25  | 50    | μA   | $V_{IN} = 5V$                |
| Logic "0" Input Bias Current                                  | I <sub>IN-</sub>   | _   | 1.0 | 2.0   | μA   | $V_{IN} = 0V$                |
| V <sub>BS</sub> Supply Undervoltage Positive Going Threshold  | V <sub>BSUV+</sub> | 7.6 | 8.4 | 9.8   | V    | —                            |
| V <sub>BS</sub> Supply Undervoltage Negative Going Threshold  | V <sub>BSUV-</sub> | 6.9 | 7.8 | 9.0   | V    | —                            |
| V <sub>CC</sub> Supply Undervoltage Positive Going Threshold  | V <sub>CCUV+</sub> | 7.6 | 8.4 | 9.8   | V    | —                            |
| V <sub>CC</sub> Supply Undervoltage Negative Going Threshold  | Vccuv-             | 6.9 | 7.8 | 9.0   | V    | —                            |
| ) ( and ) ( Lindow (alterna Livetorea)                        | V <sub>CCUVH</sub> | —   | 0.6 |       | V    | —                            |
| V <sub>CC</sub> and V <sub>BS</sub> Undervoltage Hysteresis   | VBSUVH             |     | 0.6 | _     | V    | —                            |
| Output High Short Circuit Pulsed Current                      | I <sub>O+</sub>    | 3.5 | 4.5 | _     | A    | $V_0 = 0V, PW \le 10ms$      |
| Output Low Short Circuit Pulsed Current                       | I <sub>O-</sub>    | 3.5 | 4.5 | _     | А    | $V_0$ = 15V, PW $\leq$ 10ms  |

Notes: 7. The V<sub>IN</sub> and I<sub>IN</sub> parameters are applicable to the two logic pins; HIN and LIN. The V<sub>O</sub> and I<sub>O</sub> parameters are applicable to the respective output pins: HO and LO.

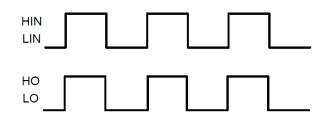
8. For optimal operation, it is recommended that the input pulses (HIN and LIN) should have a minimum amplitude of 2.5V with a minimum pulse width of 280ns.

# AC Electrical Characteristics (V<sub>BIAS</sub> (V<sub>CC</sub>, V<sub>BS</sub>) = 15V, C<sub>L</sub> = 1000pF, @T<sub>A</sub> = +25°C, unless otherwise specified.)

| Parameter                           | Symbol           | Min | Тур | Max | Unit | Condition        |
|-------------------------------------|------------------|-----|-----|-----|------|------------------|
| Turn-On Propagation Delay           | ton              | —   | 140 | 200 | ns   | $V_S = 0V$       |
| Turn-Off Propagation Delay          | t <sub>OFF</sub> | —   | 140 | 200 | ns   | $V_{\rm S} = 0V$ |
| Delay Matching, HO & LO Turn On/Off | t <sub>DM</sub>  | —   |     | 50  | ns   | —                |
| Turn-On Rise Time                   | t <sub>R</sub>   | —   | 25  | 50  | ns   | $V_{S} = 0V$     |
| Turn-Off Fall Time                  | t <sub>F</sub>   | —   | 20  | 45  | ns   | $V_{\rm S} = 0V$ |



## **Timing Waveforms**





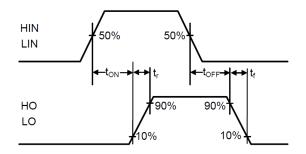


Figure 2. Switching Time Waveform Definitions

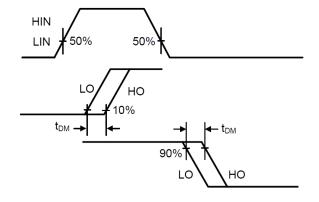


Figure 3. Delay Matching Waveform Definitions



## Typical Performance Characteristics (Vcc=15V, @T<sub>A</sub> = +25°C, unless otherwise specified.)

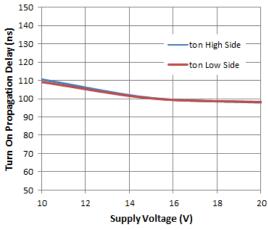


Figure 4. Turn-on Propagation Delay vs. Supply Voltage

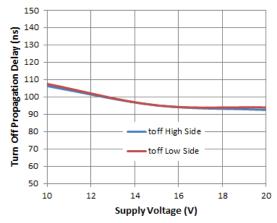
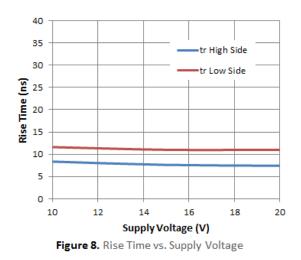


Figure 6. Turn-off Propagation Delay vs. Supply Voltage



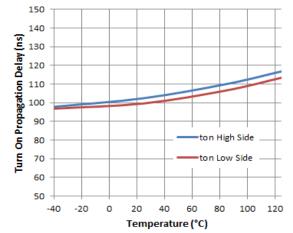


Figure 5. Turn-on Propagation Delay vs. Temperature

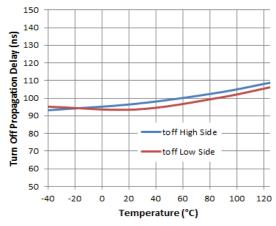
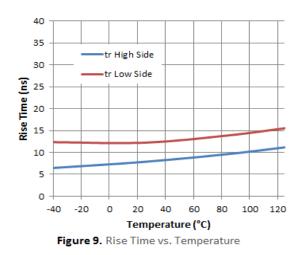


Figure 7. Turn-off Propagation Delay vs. Temperature





# Typical Performance Characteristics (continued) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

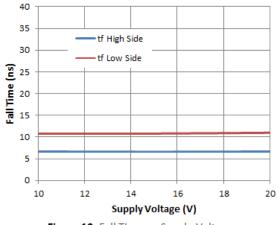


Figure 10. Fall Time vs. Supply Voltage

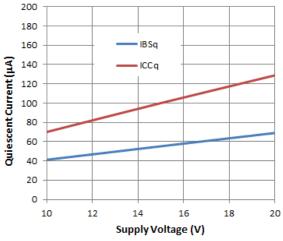
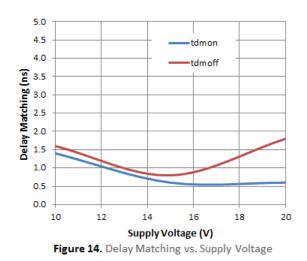


Figure 12. Quiescent Current vs. Supply Voltage



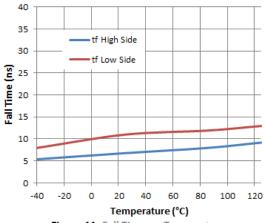
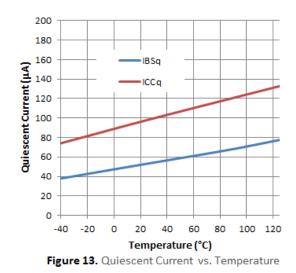
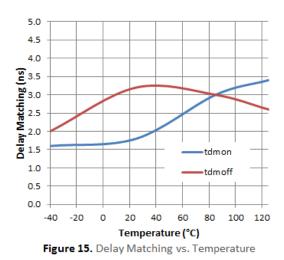


Figure 11. Fall Time vs. Temperature







### Typical Performance Characteristics (continued) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

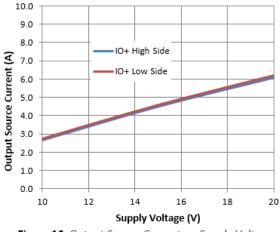


Figure 16. Output Source Current vs. Supply Voltage

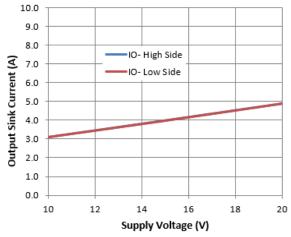


Figure 18. Output Sink Current vs. Supply Voltage

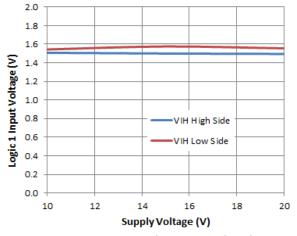


Figure 20. Logic 1 Input Voltage vs. Supply Voltage

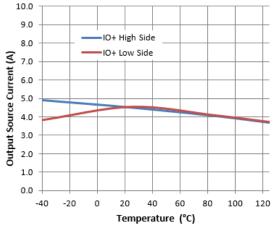
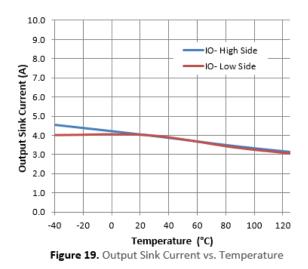
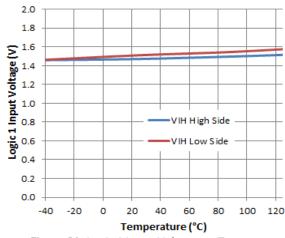
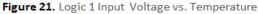


Figure 17. Output Source Current vs. Temperature









## Typical Performance Characteristics (continued) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

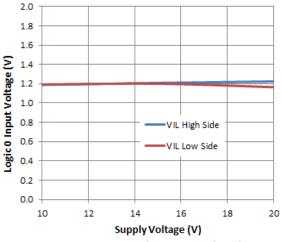
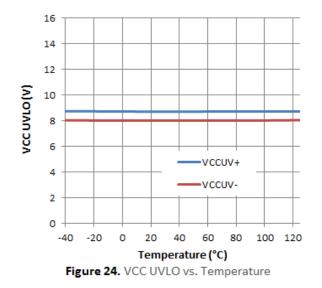


Figure 22. Logic 0 Input Voltage vs. Supply Voltage



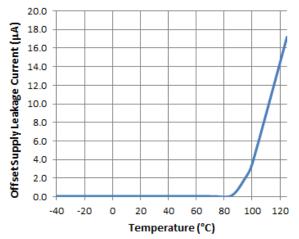


Figure 26. Offset Supply Leakage Current vs. Temperature

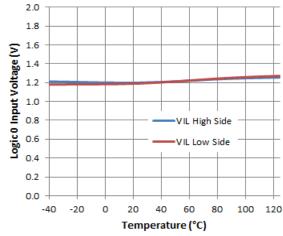
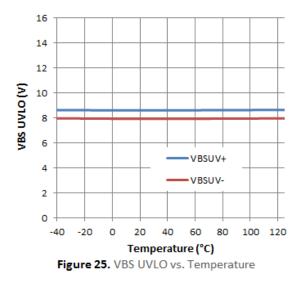


Figure 23. Logic 0 Input Voltage vs. Temperature





Max

1.75

0.25

0.51

0.248

5.00

6.20

4.00

\_

0.50

1.27

8°

Тур

\_

1.45

\_

\_

4.90

6.00

3.90

1.27

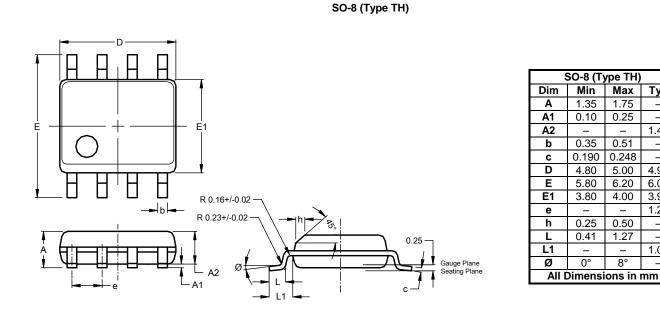
\_

\_

1.04

#### **Package Outline Dimensions**

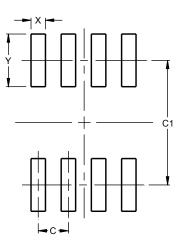
Please see http://www.diodes.com/package-outlines.html for the latest version.



#### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8 (Type TH)



| Dimensions | Value (in mm) |  |  |  |
|------------|---------------|--|--|--|
| С          | 1.27          |  |  |  |
| C1         | 5.20          |  |  |  |
| Х          | 0.60          |  |  |  |
| Y          | 2.20          |  |  |  |

For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between Note: device Terminals and PCB tracking.



#### **IMPORTANT NOTICE**

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

#### LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
  - 1. are intended to implant into the body, or
  - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2019, Diodes Incorporated

www.diodes.com